RG10

ULTRAFAST EFFICIENT PLASTIC SILICON RECTIFIER



VOLTAGE: 400V

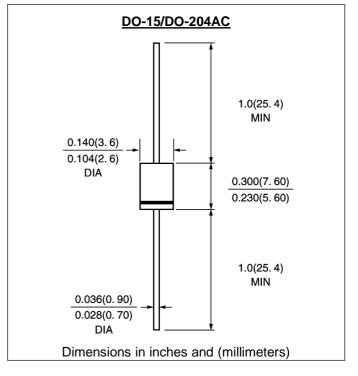
CURRENT: 1.5A

FEATURE

Low power loss High surge capability Glass passivated chip junction Ultra-fast recovery time for high efficiency High temperature soldering guaranteed 250°C/10sec/0.375″ lead length at 5 lbs tension

MECHANICAL DATA

Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
Polarity: color band denotes cathode
Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half -wave, 60HZ, resistive or inductive load rating at 25 °C, unless otherwise stated)

		SYMBOL	RG10	unite
Maximum Recurrent Peak Reverse Voltage		Vrrm	400	V
Maximum RMS Voltage		Vrms	280	V
Maximum DC blocking Voltage		Vdc	400	V
Maximum Average Forward Rectified Current 3/8"lead length at Ta =50 $^\circ\!\!\mathbb{C}$		lf(av)	1.5	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load		lfsm	50.0	A
Maximum Forward Voltage at Forward current		Vf	1.1	V
Maximum DC Reverse Current at rated DC blocking voltage	Ta =25℃ Ta =125℃	Ir	5.0 200.0	μA
Maximum Reverse Recovery Time	(Note 1)	Trr	50	nS
Typical Junction Capacitance	(Note 2)	Cj	15	pF
Typical Thermal Resistance	(Note 3)	Rth(ja)	45	°C/V
Storage and Operating Junction Temperature		Tstg,Tj	-55 to +150	°C

Note:

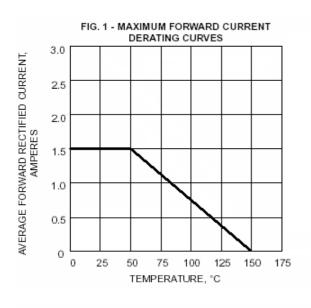
1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A

2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

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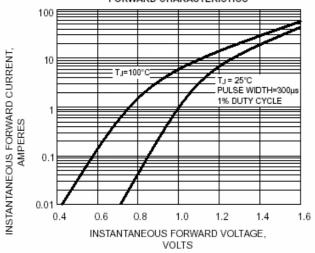
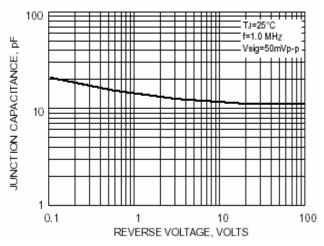


FIG. 5 - TYPICAL JUNCTION CAPACITANCE



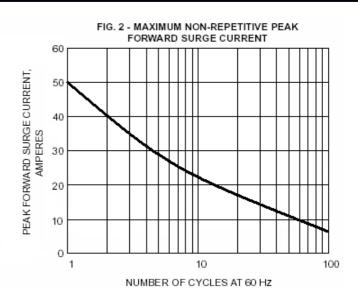


FIG. 4 - TYPICAL REVERSE LEAKAGE CHARACTERISTICS

